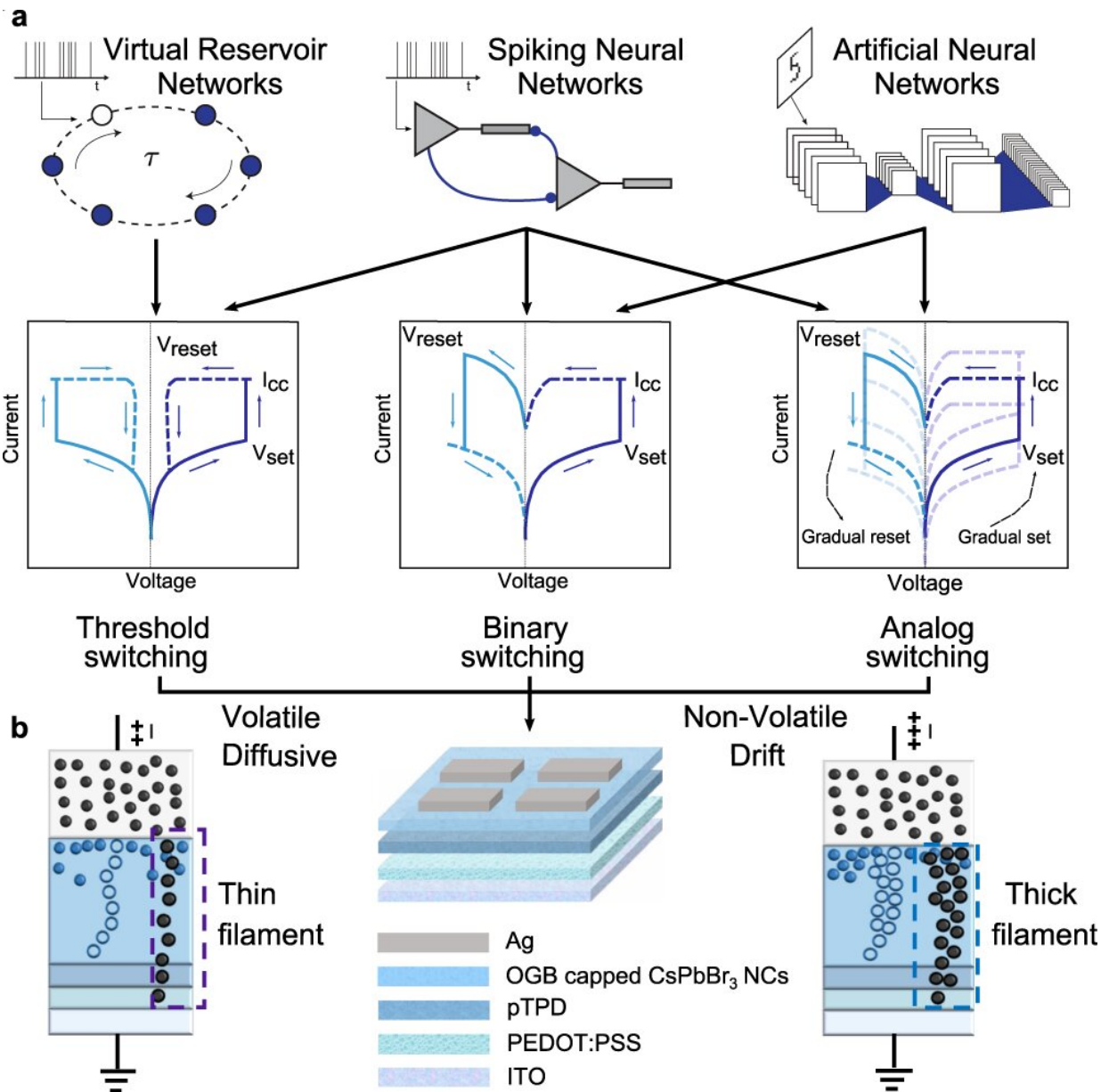


Dual-mode memristors based on perovskite nanocrystals: A component for brain-inspired computing

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The reconfigurable perovskite memristor concept. a Different neural network frameworks demand particular switching characteristics from in-memory computing implementations. For example, delay systems (dynamical non-linear systems with delayed feedback such as virtual reservoir networks), should exhibit only a fading memory to process the inputs from the recent past. Such short-term dynamics are best represented by volatile threshold-switching memristors. SNNs often demand both volatile and non-volatile dynamics, simultaneously. Synaptic mechanisms requiring STP and eligibility traces can be implemented using volatile memristors whereas synaptic efficacy requires either efficient binary-switching or analog switching devices. Lastly, ANN performances specifically benefit from non-volatile features such as multi-level bit precision of weights and linear conductance response during the training phase. b A reconfigurable memristor with active control over its diffusive and drift dynamics may be a feasible unifying solution. Schematic of the reconfigurable halide perovskite nanocrystal memristor is shown for reference. We utilize the same active switching material (CsPbBr_3 NCs capped with OGB ligands) to implement two distinct types of computation in the RC framework. The volatile diffusive mode exhibiting short-term memory is utilized as the reservoir layer while the non-volatile drift mode exhibiting long-term memory serves as the readout layer. Credit: *Nature Communications* (2022). DOI: 10.1038/s41467-022-29727-1

Compared with computers, the human brain is incredibly energy-efficient. Scientists are therefore drawing on how the brain and its interconnected neurons function for inspiration in designing innovative computing technologies. They foresee that these brain-inspired computing systems, will be more energy-efficient than conventional ones, as well as better at performing machine-learning tasks.

Much like neurons, which are responsible for both [data storage](#) and data processing in the brain, scientists want to combine storage and

processing in a single type of electronic component, known as a memristor. Their hope is that this will help to achieve greater efficiency because moving data between the processor and the storage, as conventional computers do, is the main reason for the high energy consumption in machine-learning applications.

Researchers at ETH Zurich, Empa and the University of Zurich have now developed an innovative concept for a memristor that can be used in a far wider range of applications than existing memristors. "There are different operation modes for memristors, and it is advantageous to be able to use all these modes depending on an artificial neural network's architecture," explains ETH Zurich postdoc Rohit John. "But previous conventional memristors had to be configured for one of these modes in advance." The new memristors can now easily switch between two operation modes while in use: a mode in which the signal grows weaker over time and dies (volatile mode), and one in which the signal remains constant (non-volatile mode).

Just like in the brain

"These two operation modes are also found in the [human brain](#)," John says. On the one hand, stimuli at the synapses are transmitted from neuron to neuron with biochemical neurotransmitters. These stimuli start out strong and then gradually become weaker. On the other hand, new synaptic connections to other neurons form in the brain while we learn. These connections are longer-lasting.

John, who is a postdoc in the group headed by ETH Zurich/Empa researcher Maksym Kovalenko, was awarded an ETH fellowship for outstanding postdoctoral researchers in 2020. John conducted this research together with Yiğit Demirağ, a doctoral student in Giacomo Indiveri's group at the Institute for Neuroinformatics of the University of Zurich and ETH Zurich.

Semiconductor material known from solar cells

The memristors the researchers have developed are made of halide perovskite nanocrystals, a [semiconductor material](#) known primarily from its use in photovoltaic cells. "The 'nerve conduction' in these new memristors is mediated by temporarily or permanently stringing together silver ions from an electrode to form a nanofilament penetrating the perovskite structure through which current can flow," explains Kovalenko.

This process can be regulated to make the silver-ion filament either thin, so that it gradually breaks back down into individual [silver ions](#) (volatile mode), or thick and permanent (non-volatile mode). This is controlled by the intensity of the current conducted on the memristor: Applying a weak current activates the volatile mode, while a [strong current](#) activates the non-volatile mode.

New toolkit for neuroinformaticians

"To our knowledge, this is the first [memristor](#) that can be reliably switched between volatile and non-volatile modes on demand," Demirağ says. This means that in the future, computer chips can be manufactured with memristors that enable both modes. This is a significance advance because it is usually not possible to combine several different types of memristors on one chip.

Within the scope of the study, which they recently published in the journal *Nature Communications*, the researchers tested 25 of these new memristors and carried out 20,000 measurements with them. In this way, they were able to simulate a [computational problem](#) on a complex network. The problem involved classifying a number of different neuron spikes as one of four predefined patterns.

Before these memristors can be used in computer technology, they will need to undergo further optimization. However, such components are also important for research in neuroinformatics, as Indiveri points out: "These components come closer to real neurons than previous ones. As a result, they help researchers to better test hypotheses in neuroinformatics and hopefully gain a better understanding of the computing principles of real neuronal circuits in humans and animals."

More information: Rohit Abraham John et al, Reconfigurable halide perovskite nanocrystal memristors for neuromorphic computing, *Nature Communications* (2022). [DOI: 10.1038/s41467-022-29727-1](https://doi.org/10.1038/s41467-022-29727-1)

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